Technical Data Sheet



DPDT Ramses Low PIM N 12.4GHz Failsafe 12Vdc Diodes Pins Terminals with bracket

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RF CHARACTERISTICS

Frequency range : 0 - 12.4 GHz Impedance : 50 Ohms

Frequency (GHz)	DC - 1	1 - 2	2 - 3	3 - 8	8 - 12.4
VSWR max	1.15	1.20	1.25	1.35	1.50
Insertion loss max	0.15 dB	0.20 dB	0.25 dB	0.35 dB	0.50 dB
Isolation min	85 dB	80 dB	75 dB	70 dB	60 dB
Average power (*)	700 W	500 W	400 W	250 W	200 W

	Passive intermodulation		
Tone 1	1810 MHz, approximately 43 dBm		
Tone 2	1850 MHz, approximately 43 dBm		
3 rd order PIM	- 160 dBc at 1770 MHz		

Depending on application, carrier powers and frequencies, PIM measurements can vary. PIM testing is not measured during product acceptance test.

ELECTRICAL CHARACTERISTICS

Actuator : FAILSAFE
Nominal current ** : 340 mA

Actuator voltage (Vcc) : 12V (10.2 to 13V)

Terminals : solder pins (250°C max. / 30 sec.)

MECHANICAL CHARACTERISTICS

Connectors***** : N female per MIL-C 39012

Life : 2 million cycles

Switching Time*** : < 15 ms

Construction : Splashproof

Weight : < 215 g

ENVIRONMENTAL CHARACTERISTICS

Operating temperature range : -25°C to +70°C
Storage temperature range : -55°C to +85°C

(* Average power at 25°C per RF Path)

(** At 25° C ±10%)

(*** Nominal voltage; 25° C)

(***** Recommended mating torque: 300 N.cm)



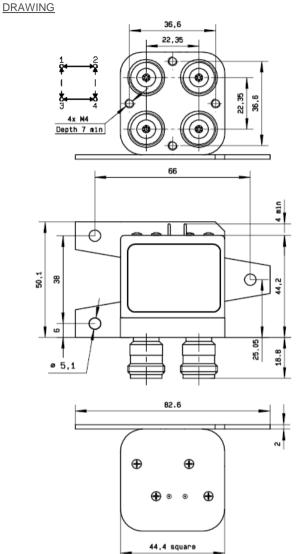


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SERIE: DPDT

LABEL

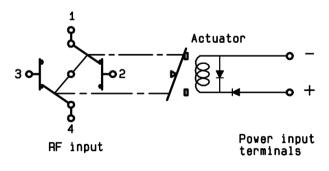




General tolerances: ±0.5 mm

SCHEMATIC DIAGRAM

Position: De energized



Voltage	RF Continuity
energized	$1 \leftrightarrow 3 / 2 \leftrightarrow 4$
De-energized	$1 \leftrightarrow 2 / 3 \leftrightarrow 4$